

Supplementary Information

Chemical reduction-induced surface oxygen vacancies of BiVO₄ photoanodes with enhanced photoelectrochemical performance

Yong Peng^{a,b,c}, Hao Wu^a, Mingjian Yuan^d, Fang-Fang Li^e, Xingli Zou^f, Yun Hau Ng^a
and Hsien-Yi Hsu^{*,a,b,c}

^a *School of Energy and Environment, City University of Hong Kong, Kowloon Tong, Hong Kong, China*

^b *Department of Materials Science and Engineering, City University of Hong Kong, Kowloon Tong, Hong Kong, China*

^c *Shenzhen Research Institute of City University of Hong Kong, Shenzhen, 518057, China*

^d *Key Laboratory of Advanced Energy Materials Chemistry (Ministry of Education), Renewable Energy Conversion and Storage Center (RECAST), College of Chemistry, Nankai University, 300071, Tianjin, P. R. China.*

^e *School of Materials Science and Engineering, Huazhong University of Science and Technology, 1037 Luoyu Road, Wuhan 430074, China*

^f *State Key Laboratory of Advanced Special Steel, School of Materials Science and Engineering, Shanghai University, Shanghai 200444, China*

***Corresponding author:**

Hsien-Yi Hsu, E-mail: sam.hyhsu@cityu.edu.hk

1. Preparation of pristine BiVO₄ films

BiVO₄ films were synthesized based on electrodeposition [1]. First, the pH of 50 mL of water in a beaker was adjusted to 1.7 by adding around 70 μ L of 65% HNO₃. Next, 3.32 g of KI (0.4 M) was added to the solution which was stirred for 5 min to dissolve KI (for stabilizing Bi(NO₃)₃). After that, 0.97 g of Bi(NO₃)₃·5H₂O (0.04 M) was added to this solution which was stirred vigorously until total dissolving. Besides, 0.497 g of *p*-benzoquinone (0.23 M) was added to 20 mL of ethanol (99.8%) which was stirred for at least 30 min. The *p*-benzoquinone in ethanol was then mixed with the KI/Bi(NO₃)₃ solution by stirring for 2 min which was used as electrolyte for electrodeposition.

Cathodic deposition was carried out using a three-electrode system in which FTO glass (sonicated in acetone, ethanol and water each for 20 min, and dried with compressed air) was as working electrode, Pt wire as counter electrode and Ag/AgCl (3 M KCl) as reference electrode. Amperometric *i*-*t* technique was employed, and the potential was set at -0.1 V vs. Ag/AgCl. Each electrodeposition was last for 5 min, and a total charge of around 0.13 C cm⁻² was finally accumulated to electrodeposit BiOI films on FTO glass. To obtain BiVO₄ films, 300 μ L of 0.2 M VO(acac)₂ in DMSO was added on each BiOI film and heated at 85 °C for 30 min to vaporize DMSO. The samples were then calcined at 450 °C for 2 h in air using a muffle furnace (ramp rate 2 °C min⁻¹). Finally, BiVO₄ films were treated in 1 M NaOH for 30 min with gentle stir to remove V₂O₅, and then rinsed with water and dried overnight in air.

2. Electrochemically active surface area (EASA) measurements

The EASA of bare BiVO₄ and S-BiVO₄ photoanodes was estimated according to a double-layer capacitance method [2, 3]. The change of current density in the dark under the bias potential is attributed to capacitive charging and not relevant to faradaic current since there is no redox couple in the electrolyte (Figure S2a and b) [2, 3]. The calculated C_{dl} values, representing the capacitance of double-layer at material surface, are 98 and 131 μF cm⁻² for bare BiVO₄ and S-BiVO₄ photoanodes, respectively (Figure S2c). The corresponding EASA could be estimated according to the below equation (Table inserted in Figure S2c).

$$\text{EASA} = \frac{C_{\text{dl}}}{C_{\text{s}}}$$

Where C_s is the capacitance of smooth planar surface of the material in the same electrolyte. Since both photoanodes basically contain BiVO₄, they are assumed to have the same C_s.

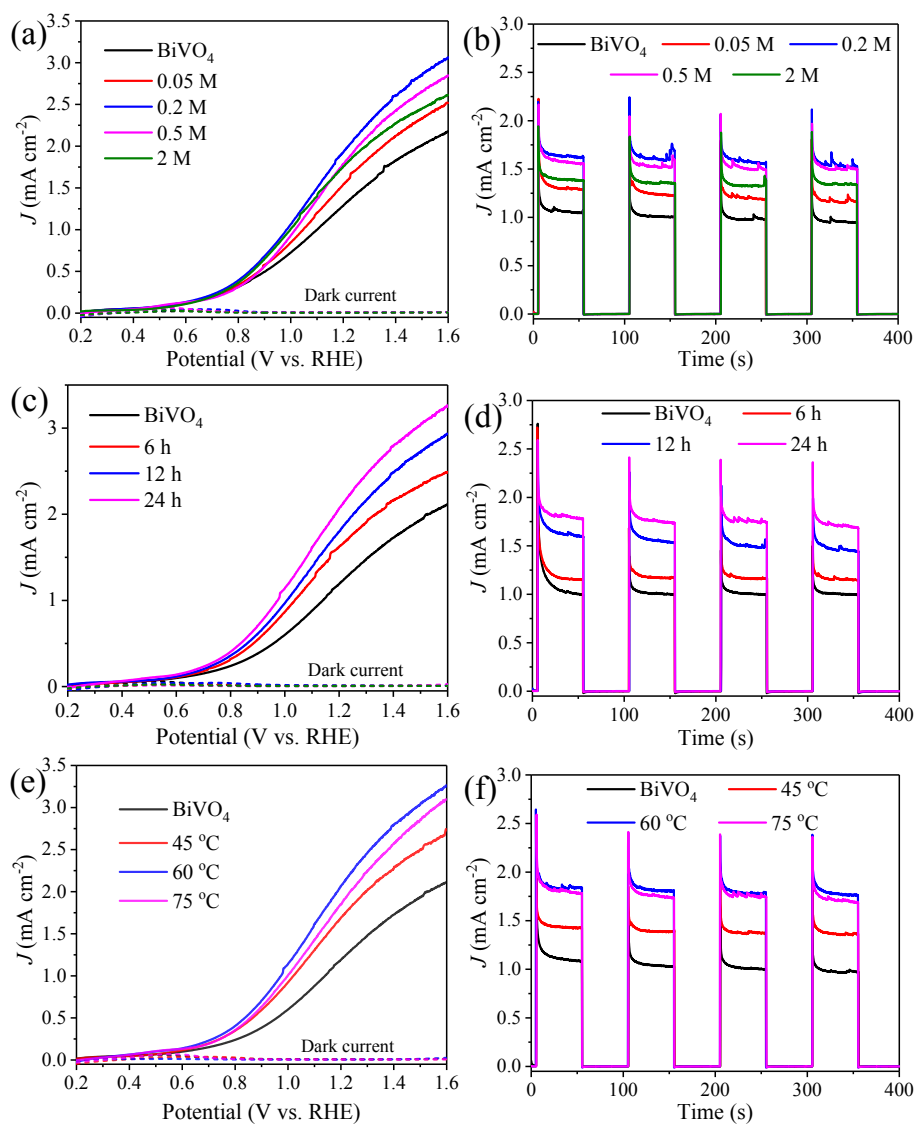


Figure S1. (a) LSV and (b) I-t responses of sulfite-treated BiVO_4 prepared by the reactions with different concentrations of Na_2SO_3 at $60\text{ }^\circ\text{C}$ for 9 h. (c) LSV and (d) I-t results of sulfite-treated BiVO_4 prepared by the reactions with 0.2 M Na_2SO_3 for different times at $60\text{ }^\circ\text{C}$. (e) LSV and (f) I-t results of sulfite-treated BiVO_4 prepared by the reaction with 0.2 M Na_2SO_3 for 24 h at various temperatures.

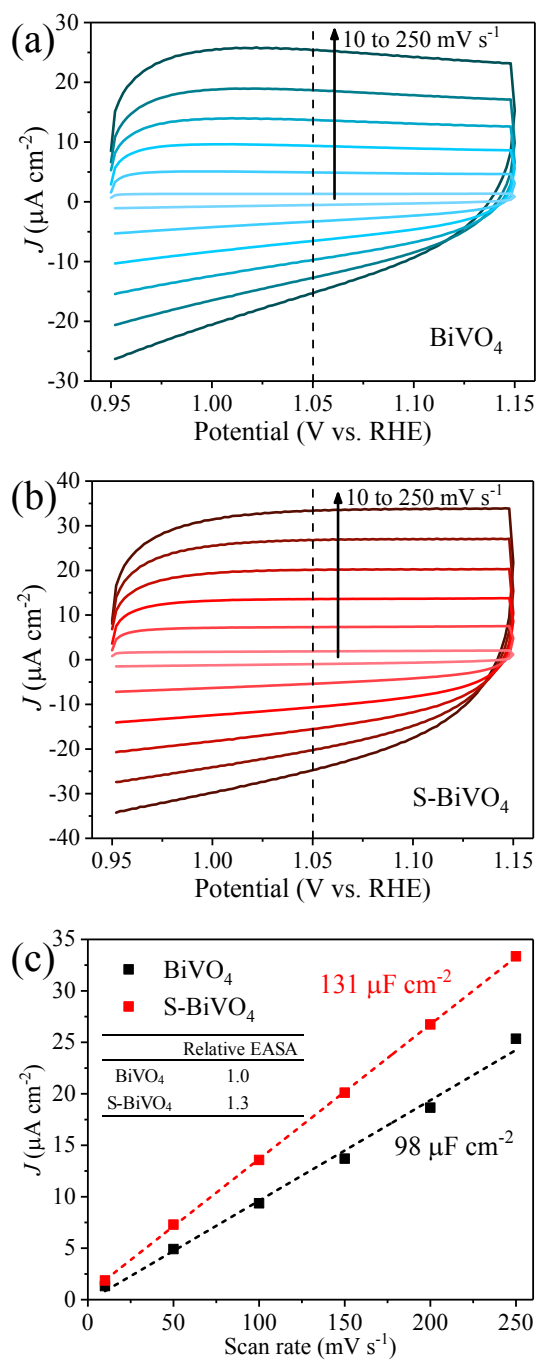


Figure S2. Cyclic voltammetry curves of (a) BiVO₄ and (b) S-BiVO₄ photoanodes at various scan rates (10, 50, 100, 150, 200 and 250 mV s^{-1}) in dark. (c) Charging current density at the potential of 1.05 V vs. RHE against scan rate.

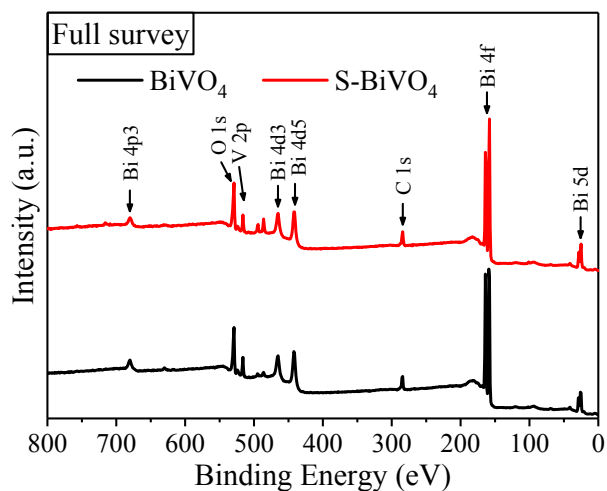


Figure S3. XPS full survey spectra of bare BiVO_4 and S-BiVO_4 photoanodes.

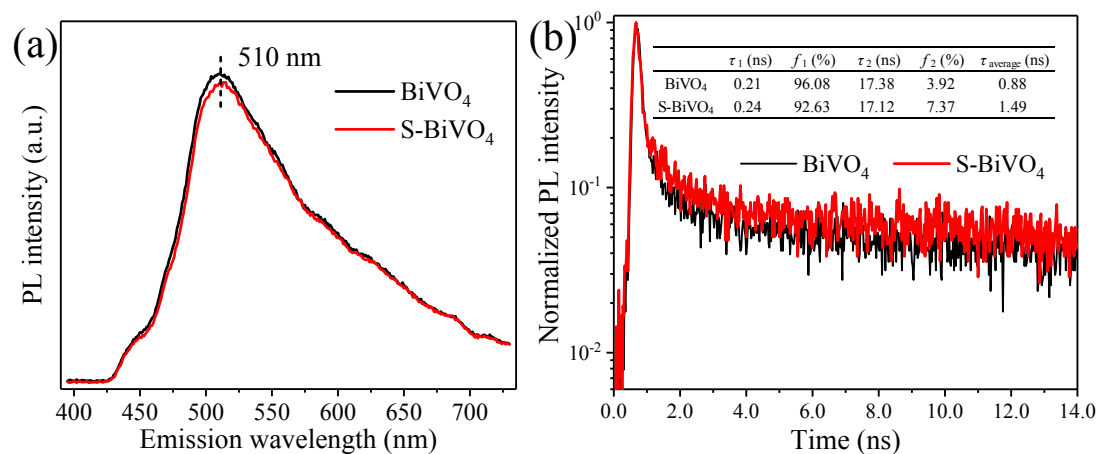


Figure S4. (a) Photoluminescence (PL) spectra of BiVO_4 and S-BiVO_4 photoanodes excited at 375 nm, and (b) Time-resolved photoluminescence (TRPL) spectra of bare BiVO_4 and S-BiVO_4 photoanodes.

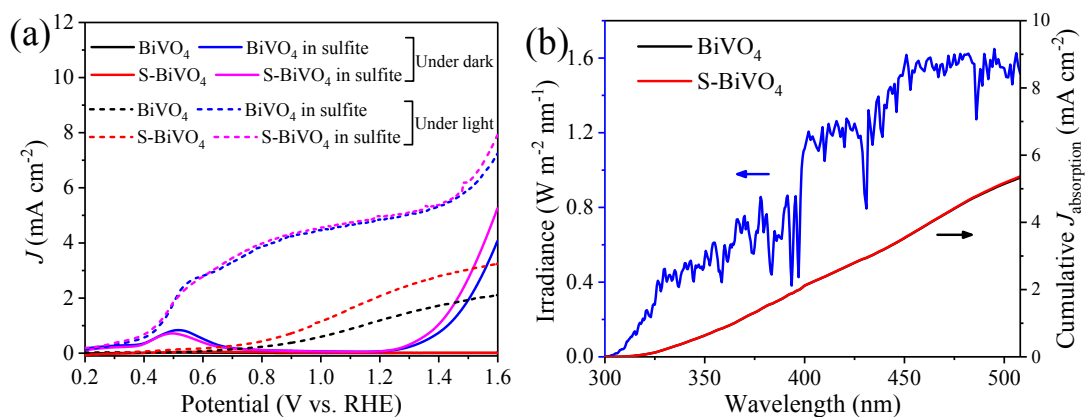


Figure S5. (a) LSV responses of BiVO₄ and S-BiVO₄ photoanodes in Na₂SO₄ (pH 6.6) and Na₂SO₃ (as hole scavenger, pH 10.6) electrolytes, respectively, under dark (solid curves) or illumination (dash curves) condition. (b) Theoretical cumulative photocurrent density from integrating light absorbance ($J_{\text{absorption}}$).

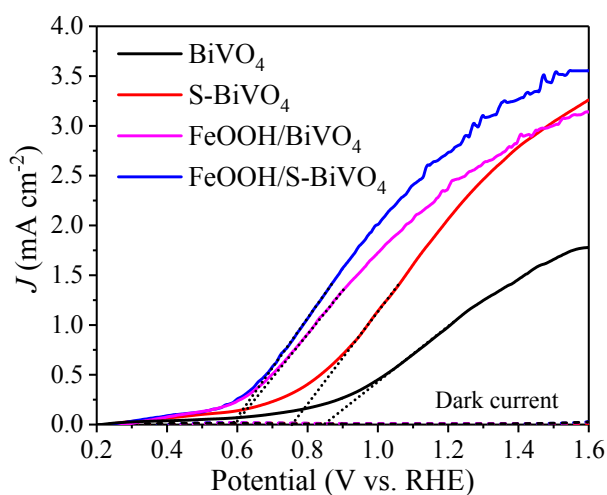


Figure S6. LSV responses of bare BiVO₄, S-BiVO₄, BiVO₄ coated by FeOOH and S-BiVO₄ coated by FeOOH.

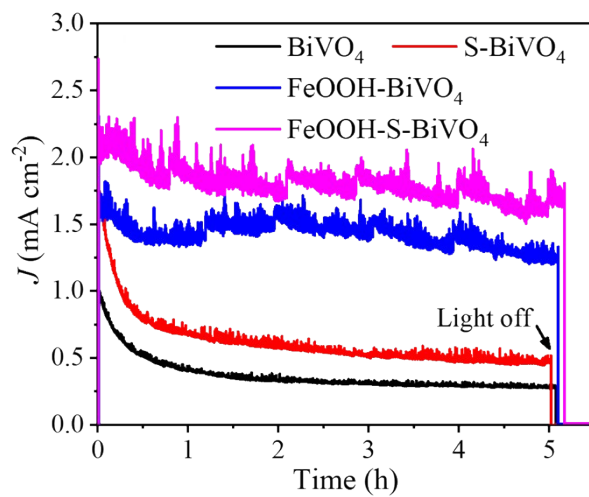


Figure S7. Amperometric i-t measurements of bare BiVO_4 , S-BiVO_4 , FeOOH-BiVO_4 and FeOOH-S-BiVO_4 photoanodes under 5-h illumination.

Table S1. Fitting parameters for electrochemical impedance spectra (EIS) of BiVO₄ and S-BiVO₄ photoanodes.

	R _s (Ω)	R _{ct} (Ω)	CPE-T (F)	CPE-P
BiVO ₄	58	851	4.8 × 10 ⁻⁵	0.75
S-BiVO ₄	54	654	4.6 × 10 ⁻⁵	0.77

Table S2. Calculated donor density of BiVO₄ and S-BiVO₄ photoanodes at various frequencies.

Sample	Donor density (×10 ⁻²⁶ m ⁻³)			
	1000 Hz	2000 Hz	4000 Hz	Average
BiVO ₄	2.88	2.48	1.76	2.37
S-BiVO ₄	5.61	4.05	3.41	4.36

Reference

- [1] T.W. Kim, K.-S. Choi, Nanoporous BiVO_4 photoanodes with dual-layer oxygen evolution catalysts for solar water splitting, *Science* 343 (2014) 990-994.
- [2] H.S. Han, S. Shin, D.H. Kim, I.J. Park, J.S. Kim, P.-S. Huang, J.-K. Lee, I.S. Cho, X. Zheng, Boosting the solar water oxidation performance of a BiVO_4 photoanode by crystallographic orientation control, *Energy Environ. Sci.* 11 (2018) 1299-1306.
- [3] X. Yin, W. Qiu, W. Li, C. Li, K. Wang, X. Yang, L. Du, Y. Liu, J. Li, High porosity Mo doped BiVO_4 film by vanadium re-substitution for efficient photoelectrochemical water splitting, *Chem. Eng. J.* 389 (2020) 124365.